DN3525

N-Channel Depletion-Mode Vertical DMOS FET

Features

- High Input Impedance
- Low Input Capacitance
- Fast Switching Speeds
- Low On-Resistance
- Free from Secondary Breakdown
- Low Input and Output Leakage

Applications

- Normally-On Switches
- Solid-State Relays
- Converters
- Constant-Current Sources
- Power Supply Circuits
- Telecommunication Switches

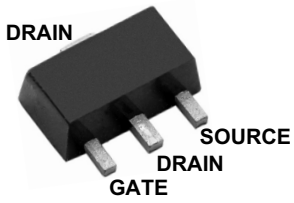
General Description

The DN3525 is a low-threshold Depletion-mode (normally-on) transistor that uses an advanced vertical DMOS structure and a well-proven silicon gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally induced secondary breakdown.

Microchip's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance and fast switching speeds are desired.

Package Type

3-lead SOT-89
(Top view)



See Table 3-1 for pin information.

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1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

Drain-to-Source Voltage ..... BV_{DSX}
Drain-to-Gate Voltage ..... BV_{DGX}
Gate-to-Source Voltage ..... ±20V
Operating Ambient Temperature, T_A ..... –55°C to +150°C
Storage Temperature, T_S ..... –55°C to +150°C

† Notice: Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Electrical Specifications: T_A = 25°C unless otherwise specified. All DC parameters are 100% tested at 25°C unless otherwise stated. Pulse test: 300 µs pulse, 2% duty cycle

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Drain-to-Source Breakdown Voltage	BV_{DSX}	250	—	—	V	V_{GS} = –5V, I_D = 100 µA
Gate-to-Source Off Voltage	$V_{GS(OFF)}$	–1.5	—	–3.5	V	V_{DS} = 15V, I_D = 1 mA
Change in $V_{GS(OFF)}$ with Temperature	$\Delta V_{GS(OFF)}$	—	—	–4.5	mV/°C	V_{DS} = 15V, I_D = 1 mA (**Note 1**)
Gate Body Leakage Current	I_{GSS}	—	—	100	nA	V_{GS} = ±20 V, V_{DS} = 0V
Drain-to-Source Leakage Current	$I_{D(OFF)}$	—	—	1	µA	V_{DS} = Maximum rating, V_{GS} = –5V
		—	—	1	mA	V_{DS} = 0.8 Maximum rating, V_{GS} = –5V, T_A = 125°C (**Note 1**)
Saturated Drain-to-Source Current	I_{DSS}	300	—	—	mA	V_{GS} = 0V, V_{DS} = 15V
Static Drain-to-Source On-State Resistance	$R_{DS(ON)}$	—	—	6	Ω	V_{GS} = 0V, I_D = 200 mA
Change in $R_{DS(ON)}$ with Temperature	$\Delta R_{DS(ON)}$	—	—	1.1	%/°C	V_{GS} = 0V, I_D = 200 mA (**Note 1**)

Note 1: Specification is obtained by characterization and is not 100% tested.

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AC ELECTRICAL CHARACTERISTICS

Electrical Specifications: T_A = 25°C unless otherwise specified. Specification is obtained by characterization and is not 100% tested.

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Forward Transconductance	G_{FS}	225	—	—	mmho	V_{DS} = 10V, I_D = 150 mA
Input Capacitance	C_{ISS}	—	270	350	pF	V_{GS} = –5V, V_{DS} = 25V, f = 1 MHz
Common Source Output Capacitance	C_{OSS}	—	20	60	pF	
Reverse Transfer Capacitance	C_{RSS}	—	5	20	pF	
Turn-On Delay Time	$t_{d(ON)}$	—	—	20	ns	V_{DD} = 25V, I_D = 150 mA, R_{GEN} = 25Ω, V_{GS} = 0V to –10V
Rise Time	t_r	—	—	25	ns	
Turn-Off Delay Time	$t_{d(OFF)}$	—	—	25	ns	
Fall Time	t_f	—	—	40	ns	
DIODE PARAMETER						
Diode Forward Voltage Drop	V_{SD}	—	—	1.8	V	V_{GS} = –5V, I_{SD} = 150 mA (**Note 1**)
Reverse Recovery Time	t_{rr}	—	800	—	ns	V_{GS} = –5V, I_{SD} = 150 mA

Note 1: Unless otherwise stated, all DC parameters are 100% tested at 25°C. Pulse test: 300 µs pulse, 2% duty cycle

TEMPERATURE SPECIFICATIONS

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
TEMPERATURE RANGE						
Operating Ambient Temperature	T_A	–55	—	+150	°C	
Storage Temperature	T_S	–55	—	+150	°C	
PACKAGE THERMAL RESISTANCE						
3-lead SOT-89	θ_{JA}	—	133	—	°C/W	

THERMAL CHARACTERISTICS

Package	I_D (**Note 1**) (Continuous) (mA)	I_D (Pulsed) (A)	Power Dissipation at T_A = 25°C (**Note 2**) (W)	I_{DR} (**Note 1**) (mA)	I_{DRM} (A)
3-lead SOT-89	360	1	1.6	360	1

Note 1: I_D (continuous) is limited by maximum T_J.

2: Mounted on an FR4 board, 25 mm x 25 mm x 1.57 mm

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2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g. outside specified power supply range) and therefore outside the warranted range.

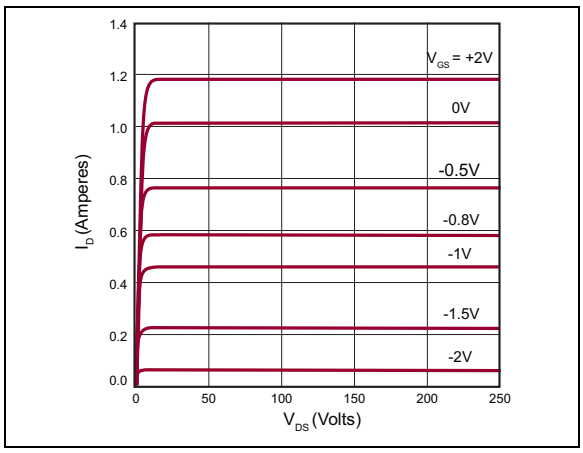


FIGURE 2-1: *Output Characteristics.*

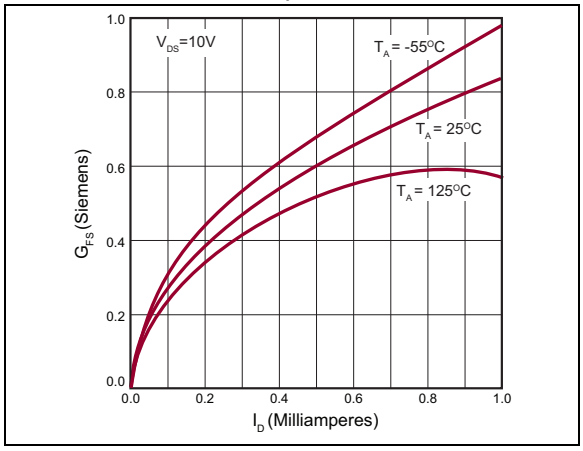


FIGURE 2-2: *Transconductance vs. Drain Current.*

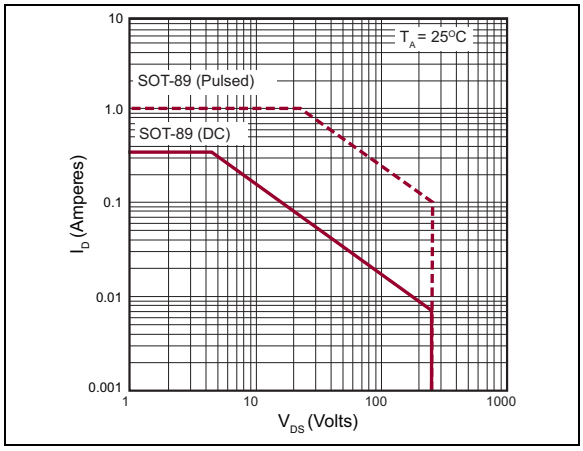


FIGURE 2-3: *Maximum Rated Safe Operating Area.*

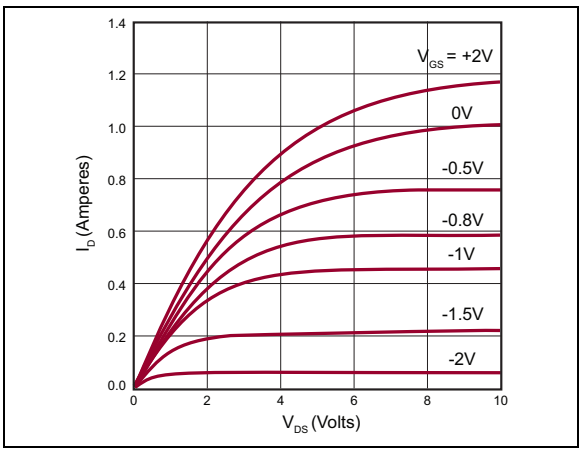


FIGURE 2-4: *Saturation Characteristics.*

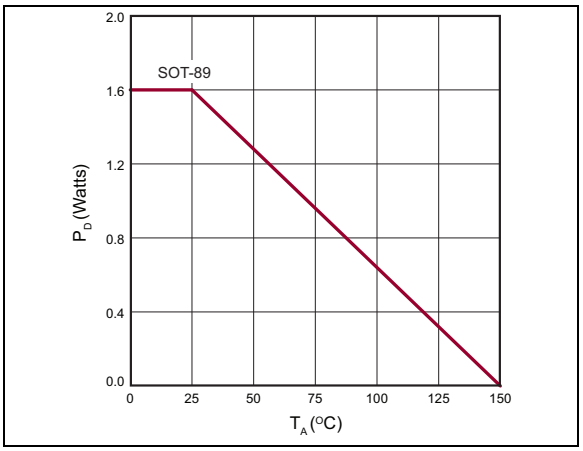


FIGURE 2-5: *Power Dissipation vs. Ambient Temperature.*

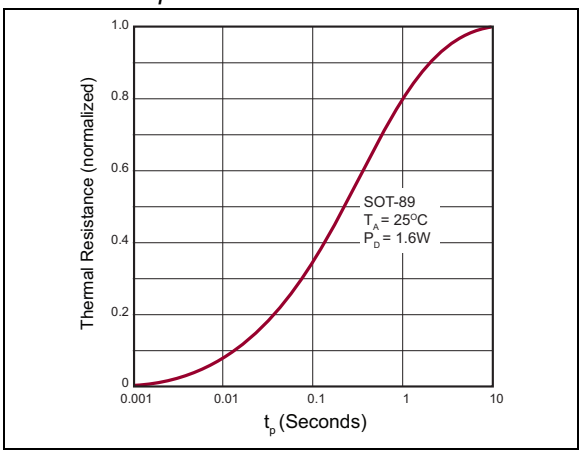


FIGURE 2-6: *Thermal Response Characteristics.*

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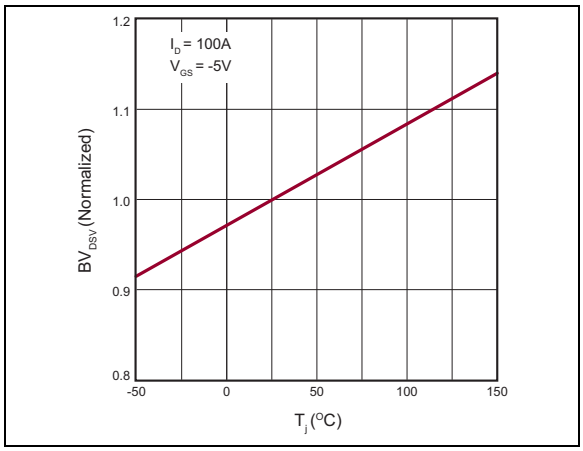


FIGURE 2-7: *BV_{DSV} Variation with Temperature.*

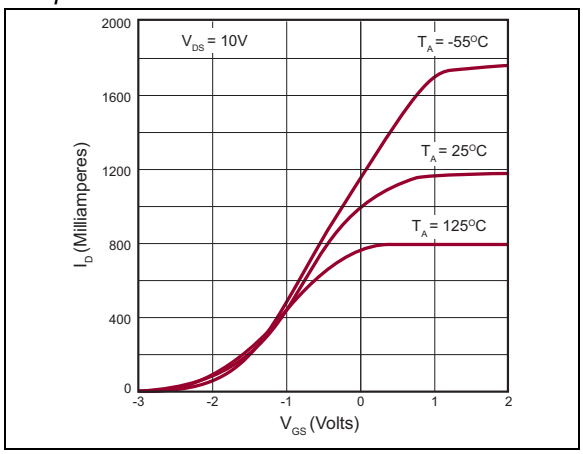


FIGURE 2-8: *Transfer Characteristics.*

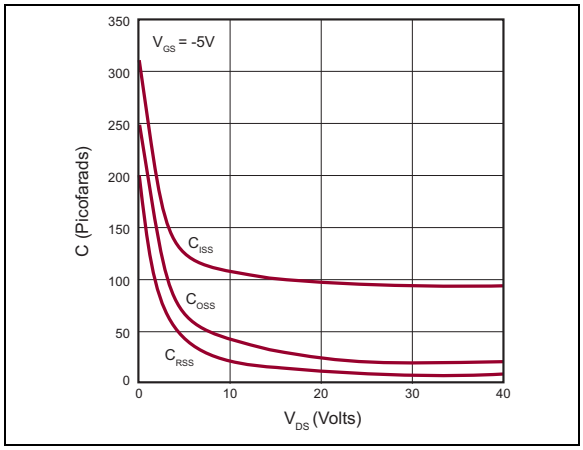


FIGURE 2-9: *Capacitance vs. Drain-to-Source Voltage.*

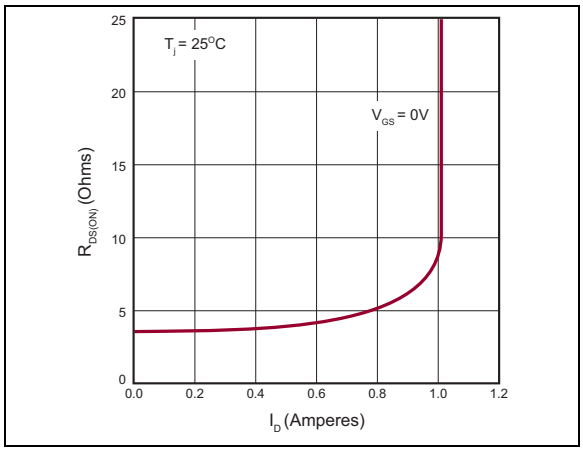


FIGURE 2-10: *On-Resistance vs. Drain Current.*

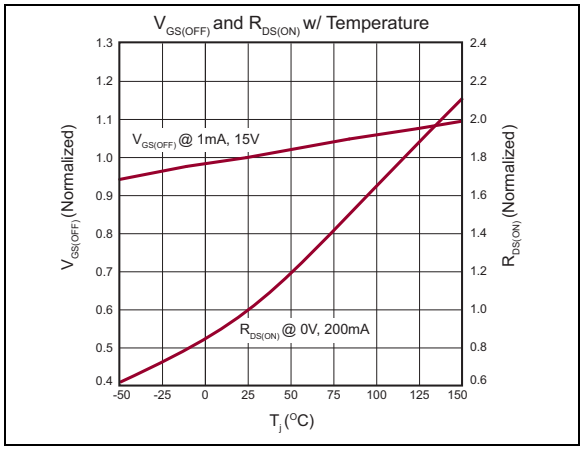


FIGURE 2-11: *$V_{GS(OFF)}$ and $R_{DS(ON)}$ with Temperature.*

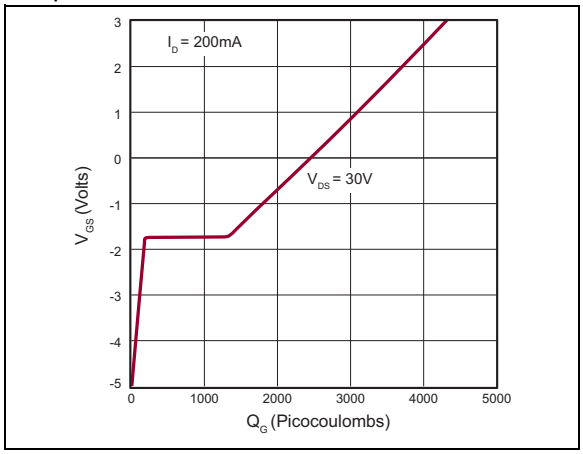


FIGURE 2-12: *Gate Drive Dynamic Characteristics.*

3.0 PIN DESCRIPTION

Table 3-1 shows the description of pins in DN3525.
Refer to **Package Type** for the location of pins.

TABLE 3-1: PIN FUNCTION TABLE

Pin Number	Pin Name	Description
1	Gate	Gate
2, 4	Drain	Drain
3	Source	Source

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4.0 FUNCTIONAL DESCRIPTION

Figure 4-1 illustrates the switching waveforms and test circuit for DN3525.

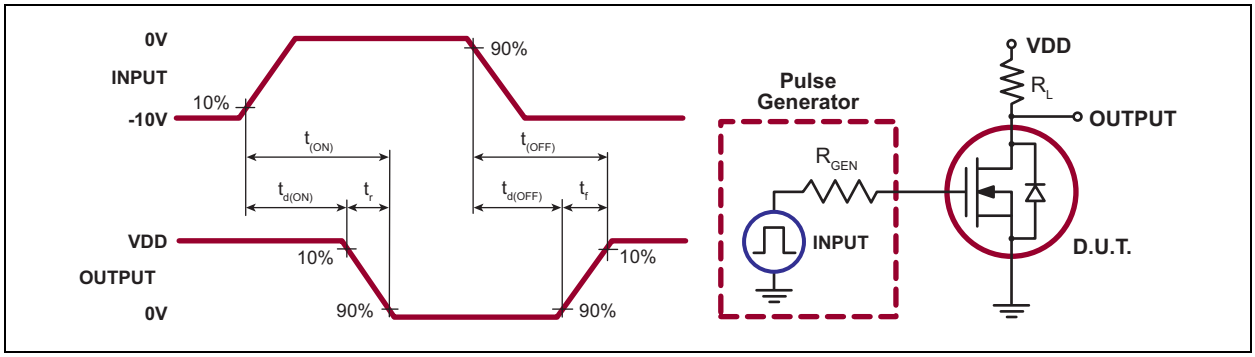


FIGURE 4-1: *Switching Waveforms and Test Circuit.*

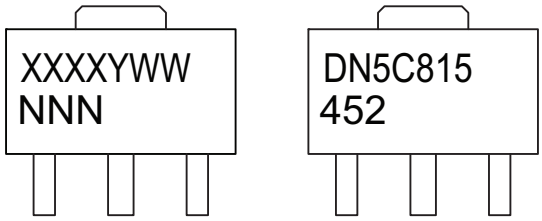
TABLE 4-1: PRODUCT SUMMARY

BV_{DSX}/BV_{DGX} (mA)	$R_{DS(ON)}$ (Maximum) (Ω)	I_{DSS} (Minimum) (mA)
250	6	300

5.0 PACKAGING INFORMATION

5.1 Package Marking Information

3-lead SOT-89 Example

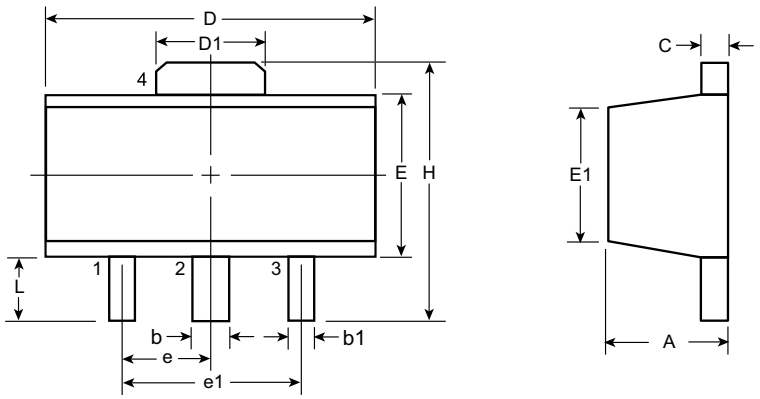


Legend:	XX...X	Product Code or Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for product code or customer-specific information. Package may or not include the corporate logo.

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3-Lead TO-243AA (SOT-89) Package Outline (N8)



Top View **Side View**

Note: For the most current package drawings, see the Microchip Packaging Specification at www.microchip.com/packaging.

Symbol		A	b	b1	C	D	D1	E	E1	e	e1	H	L
Dimensions (mm)	MIN	1.40	0.44	0.36	0.35	4.40	1.62	2.29	2.00†	1.50 BSC	3.00 BSC	3.94	0.73†
	NOM	-	-	-	-	-	-	-	-			-	-
	MAX	1.60	0.56	0.48	0.44	4.60	1.83	2.60	2.29			4.25	1.20

JEDEC Registration TO-243, Variation AA, Issue C, July 1986.
† This dimension differs from the JEDEC drawing
***Drawings not to scale**.*

NOTES:

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APPENDIX A: REVISION HISTORY

Revision A (May 2018)

- Converted Supertex Doc# DSFP-DN3525 to Microchip DS20005705A
- Added a pin function table
- Changed the package marking format
- Made minor text changes throughout the document

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	XX	-	X	-	X
Device	Package Options		Environmental		Media Type

Device:	DN3525	=	N-Channel Depletion-Mode Vertical DMOS FET
Package:	N8	=	3-lead SOT-89
Environmental:	G	=	Lead (Pb)-free/RoHS-compliant Package
Media Type:	(blank)	=	2000/Reel for an N8 Package

Example:

a) DN3525N8-G: N-Channel Depletion-Mode Vertical DMOS FET, 3-lead SOT-89, 2000/Reel

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Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

www.entegreci.com

Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

www.entegreci.com | **destek@entegreci.com** | **0850 305 90 34**

Entegreci is an online electronic components store based in Türkiye. Search by manufacturer part number to see stock, prices and datasheets for integrated circuits, microcontrollers, transistors, passive components and connectors, or request a quote for parts that are not listed.

Bu sayfa Entegreci tarafından eklenmiştir. Belgenin önceki sayfaları asıl yayıncısına aittir ve içeriği değiştirilmemiştir; en güncel sürüm için belgenin yayıncısına başvurun.